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SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT

### **CONVEYING PARTY DATA**

Name	Execution Date
Ritwik Chatterjee	12/18/2007
Eddie Acosta	12/18/2007
Varughese Mathew	12/18/2007

#### **RECEIVING PARTY DATA**

Name:	Freescale Semiconductor, Inc.	
Street Address:	6501 William Cannon Drive West	
Internal Address:	Law Department	
City:	Austin	
State/Country:	TEXAS	
Postal Code:	78735	

## PROPERTY NUMBERS Total: 1

Property Type	Number	
Application Number:	11966126	

### **CORRESPONDENCE DATA**

Fax Number: (512)996-6854

Correspondence will be sent via US Mail when the fax attempt is unsuccessful.

Phone: 512-996-6839

Email: pat.thomas@freescale.com

Correspondent Name: Pat Thomas

Address Line 1: 7700 Wesr Parmer Lane

Address Line 2: TX32/PL02

Address Line 4: Austin, TEXAS 78729

ATTORNEY DOCKET NUMBER: MT10913TP

NAME OF SUBMITTER: Pat Thomas

Total Attachments: 4

PATENT REEL: 020302 FRAME: 0775

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> PATENT REEL: 020302 FRAME: 0776

# ASSIGNMENT AND AGREEMENT

For good and valuable consideration, the receipt of which is hereby acknowledged, we, RITWIK CHATTERJEE, AUSTIN, TEXAS; EDDIE ACOSTA, MARTINDALE, TEXAS; and, VARUGHESE MATHEW, AUSTIN, TEXAS, have sold, assigned and transferred, and do hereby sell, assign and transfer, unto FREESCALE SEMICONDUCTOR, INC., a corporation of the State of Delaware, having its principal office in Austin, State of Texas, United States of America, and its successors, assigns, and legal representatives, the entire right, title and interest for the United States of America in and to certain inventions relating to improvements in FORMING A 3-D SEMICONDUCTOR DIE STRUCTURE WITH AN INTERMETALLIC FORMATION (Docket No. MT10913TP), described, illustrated and claimed in an application for Letters Patent of the United States of America executed by us on the dates indicated by our signatures below, together with the entire right, title and interest in and to the application, and in and to Letters Patent which may be issued upon the application, and

We hereby also sell, assign and transfer unto FREESCALE SEMICONDUCTOR, INC., the entire right, title and interest in and to the invention and in and to applications for Letters Patent therefor in all countries foreign to the United States of America, including all rights under any and all international conventions and treaties in respect of the invention and the applications for Letters Patent in foreign countries, and we further authorize FREESCALE SEMICONDUCTOR, INC. to apply for Letters Patent in foreign countries directly in its own name, and to claim priority of the filing date of the application for Letters Patent of the United States of America under the provisions of any and all international conventions and treaties.

upon any division, extension, continuation or reissue thereof.

We hereby authorize and request the Commissioner of Patents of the United States of America to issue Letters Patent upon the aforesaid application, division, extension, continuation or reissue, to FREESCALE SEMICONDUCTOR, INC., for the sole use and benefit of FREESCALE SEMICONDUCTOR, INC., its successors, assigns and legal representatives, to the full end of the term for which Letters Patent may be granted, the same as they would have been held and enjoyed by me had this assignment not been made, and we hereby authorize and request the equivalent authorities in foreign countries to issue the patents of their respective countries to FREESCALE SEMICONDUCTOR, INC.

We agree that, when requested, we will, without charge to FREESCALE SEMICONDUCTOR, INC., but at its expense, sign all papers, take all rightful oaths, and do all acts which may be necessary, desirable or convenient for securing and maintaining patents for

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the inventions in any and all countries and for vesting title thereto in FREESCALE SEMICONDUCTOR, INC., its successors, assigns and legal representatives or nominees.

We covenant with FREESCALE SEMICONDUCTOR, INC., its successors, assigns and legal representatives, that the interest and property hereby conveyed is free from all prior assignment, grant, mortgage, license or other encumbrance.

ihih Phatteyer DATE: 12/18/2007

First Witness

astilo date: \_\_

Second Witness

SIGNATURE OF WITNESS

LEKRERO

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EDDIE ACOSTA	DATE: 12 - 18 - 37
First Witness  SIGNATURE OF WITNESS  Esther O. Castillo PRINTED NAME OF WITNESS	DATE: /3/18/07 (Month-Day-Year)
Second Witness  SIGNATURE OF WITNESS  Cloria M. Guerero PRINTED NAME OF WITNESS	DATE: /ə//8/01 (Month-Day-Year)

VARUGHESE MATHEW	DATE: 12/18/2007
First Witness	
SIGNATURE OF WITNESS	DATE: 12/18/07 (Month-Day-Year)
FURT JUNKER- PRINTED NAME OF WITNESS	
Second Witness  JOSIA LIERRERO  SIGNATURE OF WITNESS  GLORIA M. GUERRERO	DATE: /2-/8-07 (Month-Day-Year)
PRINTED NAME OF WITNESS	

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**PATENT** 

REEL: 020302, FRAME: 0780